





60V PNP MEDIUM POWER TRANSISTOR IN SOT23

Features

- BV_{CEO} > -60V
- I_C = -1A High Continuous Collector Current
- I_{CM} = -2A Peak Pulse Current
- R_{SAT} = 295mΩ for a Low Equivalent On-Resistance
- Excellent h_{FE} Characteristics up to -2A
- Complementary NPN Type: FMMT491
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

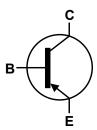
- Case: SOT23
- Case Material: molded plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (2)
- Weight 0.008 grams (approximate)

Applications

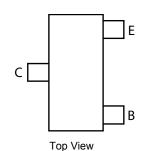
- MOSFET Gate Driving
- Power Switches
- Motor Control







Device Symbol



Pin-Out

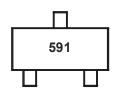
Ordering Information (Notes 4 & 5)

Part Number	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT591TA	AEC-Q101	591	7	8	3,000
FMMT591QTA	Automotive	591	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



591 = Product Type Marking Code





Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-80	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-1	Α
Peak Pulse Current	I _{CM}	-2	Α
Base Current	I _B	-200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 6)	P _D	500	mW
Thermal Resistance, Junction to Ambient (Note 6)		$R_{\theta JA}$	250	°C/W
Thermal Resistance, Junction to Lead (Note 7)		$R_{\theta JL}$	197	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Notes:

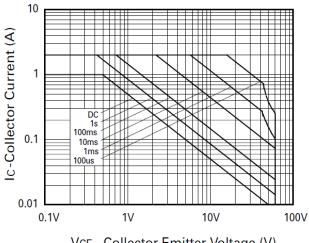
^{6.} For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

^{7.} Thermal resistance from junction to solder-point (at the end of the collector lead).

^{8.} Refer to JEDEC specification JESD22-A114 and JESD22-A115.

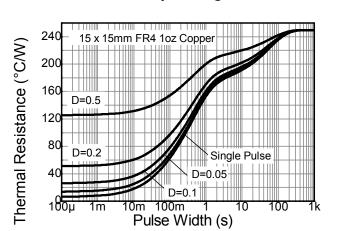


Thermal Characteristics and Derating Information

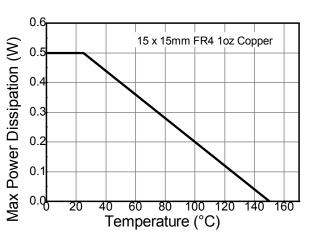


VCE - Collector Emitter Voltage (V)

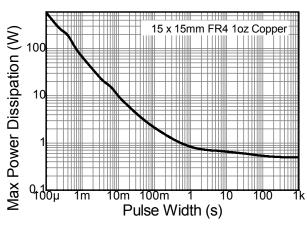
Safe Operating Area



Transient Thermal Impedance



Derating Curve



Pulse Power Dissipation





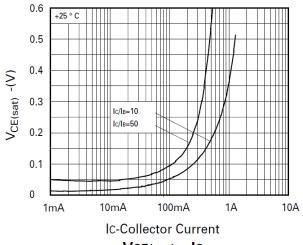
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

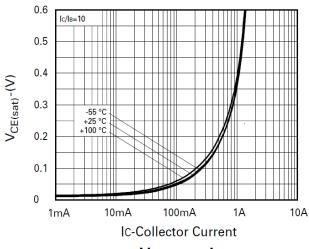
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-80	_	_	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-60	_	_	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.1	_	V	I _E = -100μA
Collector-Base Cutoff Current	I _{CBO}	_	<1	-100	nA	V _{CB} = -60V
Emitter-Base Cutoff Current	I _{EBO}	_	<1	-100	nA	V _{EB} = -5.6V
Collector-Emitter Cut-Off Current	I _{CES}	_	<1	-100	nA	V _{CE} = -50V
Static Forward Current Transfer Ratio (Note 9)	h _{FE}	100 100 80 15	220 175 155 40	300 — —	_	I_{C} = -1mA, V_{CE} = -5V I_{C} = -500mA, V_{CE} = -5V I_{C} = -1A, V_{CE} = -5V I_{C} = -2A, V_{CE} = -5V
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(SAT)}		-155 -295	-180 -350	mV	I _C = - 500mA, I _B = -50mA I _C = - 1A, I _B = -100mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE(SAT)}	_	965	-1200	mV	I _C = -1A, I _B = -100mA
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(ON)}	_	830	-1000	mV	I _C = -1A, V _{CE} = -5V
Transition Frequency	f _T	150	_	_	MHz	V _{CE} = -10V, I _C = -50mA, f = 100MHz
Output Capacitance	C _{obo}	_	_	10	pF	V _{CB} = -10V, f = 1MHz

Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

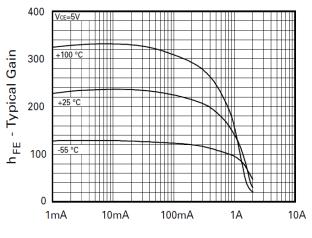


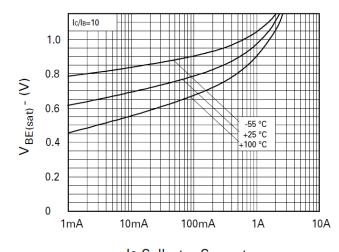
Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)





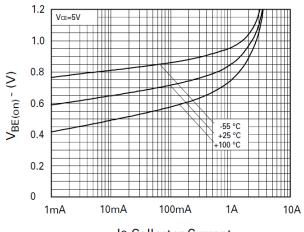
VCE(sat) v IC





Ic-Collector Current **hFE V IC**

VBE(sat) v Ic

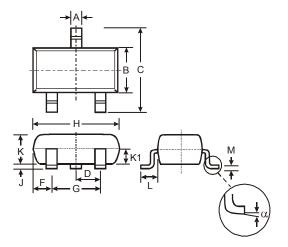


IC-Collector Current **VBE(on) v IC**



Package Outline Dimensions

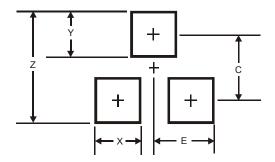
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
C	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.903	1.10	1.00		
K1	-	-	0.400		
L	0.45	0.61	0.55		
М	0.085	0.18	0.11		
α	0°	8°	-		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
Z	2.9		
Х	0.8		
Υ	0.9		
С	2.0		
E	1.35		





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